imall

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BC846ASQ

65V DUAL NPN SMALL SIGNAL TRANSISTOR

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

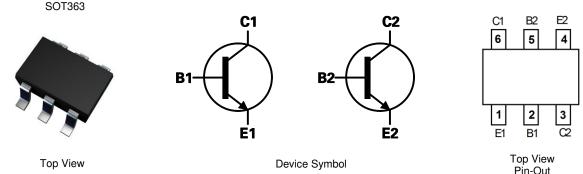
Features

- $BV_{CEO} > 65V$
- I_C = 100mA High Collector Current •
- Complementary PNP Types Available (BC856ASQ)
- Ideally Suited for Automatic Insertion •
- For Switching and AF Amplifier Applications •
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2) •
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

SOT363

Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020 •
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 @3)
- Weight: 0.006 grams (Approximate)



Ordering Information (Notes 4 and 5)

-					
Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
BC846ASQ-7-F	Automotive	KNS	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds. 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/product-compliance-definitions/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

	SC	DT	363				
				Π			
KNS YM							
KNS AW							

KNS = Product Type Marking Code YM = Date Code Marking Y = Year (ex: D = 2016) M = Month (ex: 9 = September)

Date Code Key

Notes:

Year	2016		2017	2018		2019	2020		2021	2022		2023
Code	D		E	F		G	Н			J		K
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	80	V
Collector-Emitter Voltage	V _{CEO}	65	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current	Ic	100	mA
Peak Collector Current	I _{CM}	200	mA
Peak Emitter Current	I _{EM}	200	mA

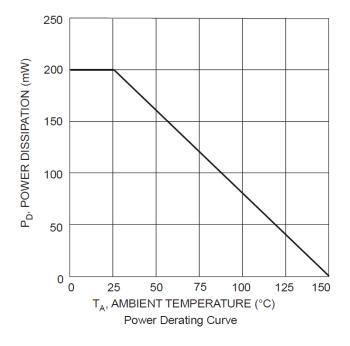
Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	200	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{ heta JA}$	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 6. For a device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper; device is measured under still air conditions whilst operating in a steady-state. 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





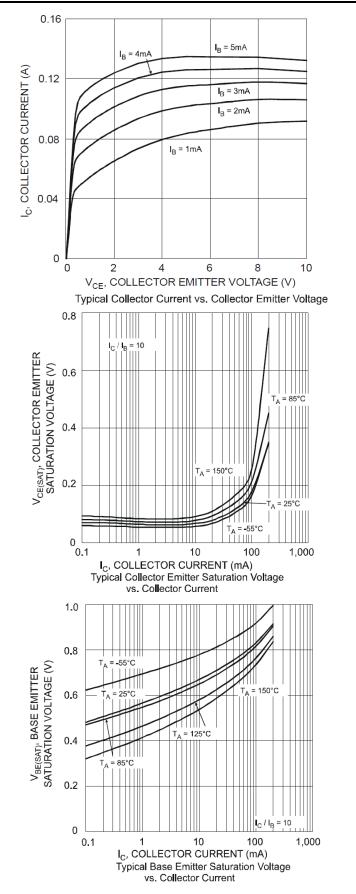
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

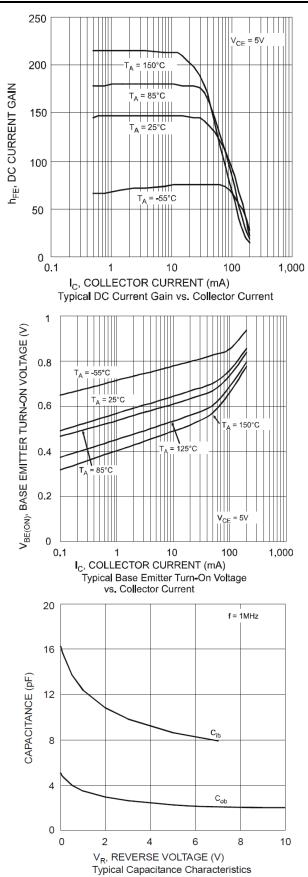
Characteristic (Note 8)	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	80	_	—	V	I _C = 10μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	65	—	-	V	$I_{C} = 10 \text{mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	6	—	-	V	$I_E = 1 \mu A$
DC Current Gain	h _{FE}	110	—	220	_	$V_{CE} = 5.0V, I_{C} = 2.0mA$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	90 200	250 600	mV	$I_{C} = 10mA, I_{B} = 0.5mA$ $I_{C} = 100mA, I_{B} = 5.0mA$
Base-Emitter Saturation Voltage	V _{BE(SAT)}		700 900	—	mV	$I_{C} = 10mA, I_{B} = 0.5mA$ $I_{C} = 100mA, I_{B} = 5.0mA$
Base-Emitter Voltage	V _{BE(ON)}	580 —	660 —	700 770	mV	$V_{CE} = 5.0V, I_C = 2.0mA$ $V_{CE} = 5.0V, I_C = 10mA$
Collector-Cutoff Current	ICES ICBO ICBO			15 15 5.0	nA nA μA	V _{CE} = 80V V _{CB} = 40V V _{CB} = 30V, T _A = +150°C
Gain Bandwidth Product	f _T	100	_	_	MHz	$\label{eq:VCE} \begin{array}{l} V_{CE} = 5.0V, \ I_C = 10 m A, \\ f = 100 M Hz \end{array}$
Collector-Base Capacitance	Ссв	_	2	_	pF	V _{CB} = 10V, f = 1.0MHz

Note: 8. For Short duration pulse test used to minimize self-heating effect.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

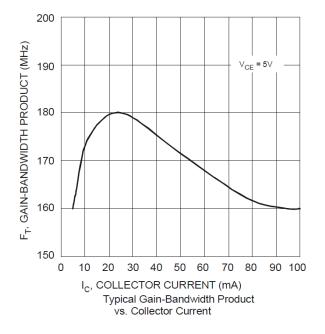




BC846ASQ Document number: DS39270 Rev. 2 - 2



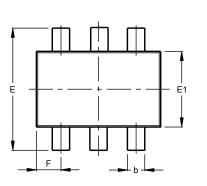
Typical Electrical Characteristics (Cont. @TA = +25°C, unless otherwise specified.)

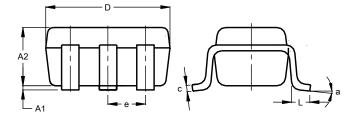




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

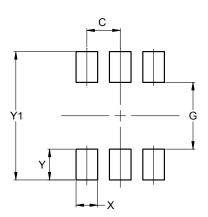




	SOT363								
Dim	Min	Max	Тур						
A1	0.00	0.10	0.05						
A2	0.90	1.00	1.00						
b	0.10	0.30	0.25						
С	0.10	0.22	0.11						
D	1.80	2.20	2.15						
Е	2.00	2.20	2.10						
E1	1.15	1.35	1.30						
е	C).650 E	SC						
F	0.40	0.45	0.425						
L	0.25	0.40	0.30						
а	0°	8°							
All	Dimen	sions	in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT363

SOT363

Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
Y1	2.500



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